

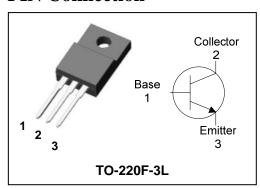
# STC603PI

**NPN Silicon Transistor** 

#### **Features**

- Power Transistor General Purpose application
- $\bullet$  Low saturation voltage :  $V_{\text{CE(SAT)}} {=}\, 0.4 V$  Typ.
- High Voltage: V<sub>CEO</sub>=60V Min.

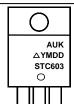
#### **PIN Connection**



### **Ordering Information**

Type NO.	Marking Package Code		
STC603PI	STC603	TO-220F-3L	

#### **Marking Diagram**



Column 1 : Manufacturer

Column 2 : Production Information
- △ : Factory Management Code

- YMDD : Date Code (Year, Month, Date)

Column 3 : Device Code

### **Absolute maximum ratings**

Characteristic	Symbol	Rating	Unit
Collector-base voltage	$V_{CBO}$	80	V
Collector-emitter voltage	$V_{\sf CEO}$	60	V
Emitter-base voltage	$V_{EBO}$	5	V
Collector current	I <sub>C</sub>	3	А
Collector power dissipation (Tc=25℃)	P <sub>C</sub>	15	W
Junction temperature	Tj	150	°C
Storage temperature	$T_{stg}$	-55~150	°C

Characteristic		Symbol	Typ.	Max.	Unit	
Thermal resistance	Junction-case	R <sub>th(J-C)</sub>	-	8.33	°C/W	

## **Electrical Characteristics**

Charac	eteristic	Symbol	Test Condition	Min.	Typ.	Max.	Unit
Collector-emitter breakdown voltage		BV <sub>CEO</sub>	I <sub>C</sub> =50mA, I <sub>B</sub> =0	60	-	-	V
Collector cut-off cu	urrent	I <sub>CBO</sub>	V <sub>CB</sub> =60V, I <sub>E</sub> =0	-	-	50	μА
Emitter cut-off cur	rent	I <sub>EBO</sub>	V <sub>EB</sub> =5V, I <sub>C</sub> =0	-	-	50	μА
DC current gain		h <sub>FE</sub> *	V <sub>CE</sub> =5V, I <sub>C</sub> =0.5A	200	-	400	-
Base-emitter on vo	oltage	V <sub>BE(ON)</sub>	V <sub>CE</sub> =5V, I <sub>C</sub> =0.5A	-	0.7	1	V
Collector-emitter s	saturation voltage	V <sub>CE(sat)</sub>	I <sub>C</sub> =2A, I <sub>B</sub> =0.2A	1	0.4	1	V
Transition frequen	су	f <sub>T</sub>	V <sub>CB</sub> =5V, I <sub>C</sub> =0.5A	-	30	-	МН
Collector output capacitance		C <sub>ob</sub>	V <sub>CB</sub> =10V, I <sub>E</sub> =0, f=1MHz	-	20	-	pF
Switching Time	Turn-on Time	T <sub>on</sub>	NPUT IBI 15Ω VCC=30V	-	0.65	-	
	Storage Time	T <sub>stg</sub>		-	1.3	-	μs
	Fall Time	$T_f$		-	0.65	-	

<sup>\*</sup> hFE rank : 200~400 Only

#### **Electrical Characteristic Curves**

Fig. 1  $P_C$  - Ta

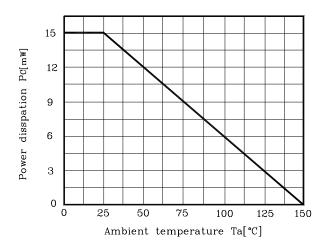


Fig. 2  $V_{\text{CE}(\text{sat})}$  -  $I_{\text{C}}$ 

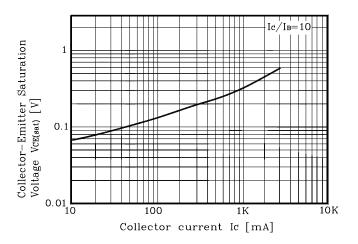


Fig. 3  $h_{\text{FE}}$ - $I_{\text{C}}$ 

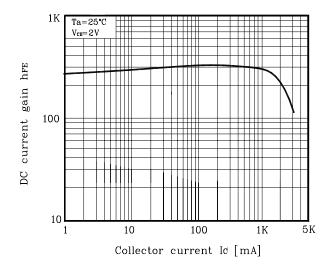


Fig. 4  $I_C$  -  $V_{CE}$ 

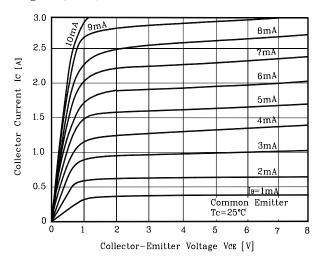
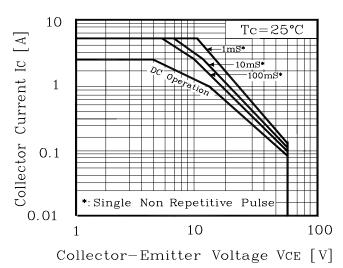


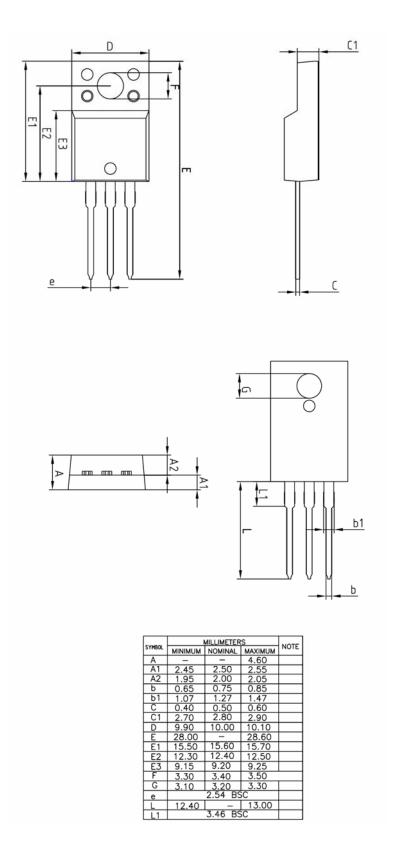
Fig. 5 Safe Operating Area



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## **Outline Dimension**



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